

SCHOTTKY RECTIFIER

3 Amp

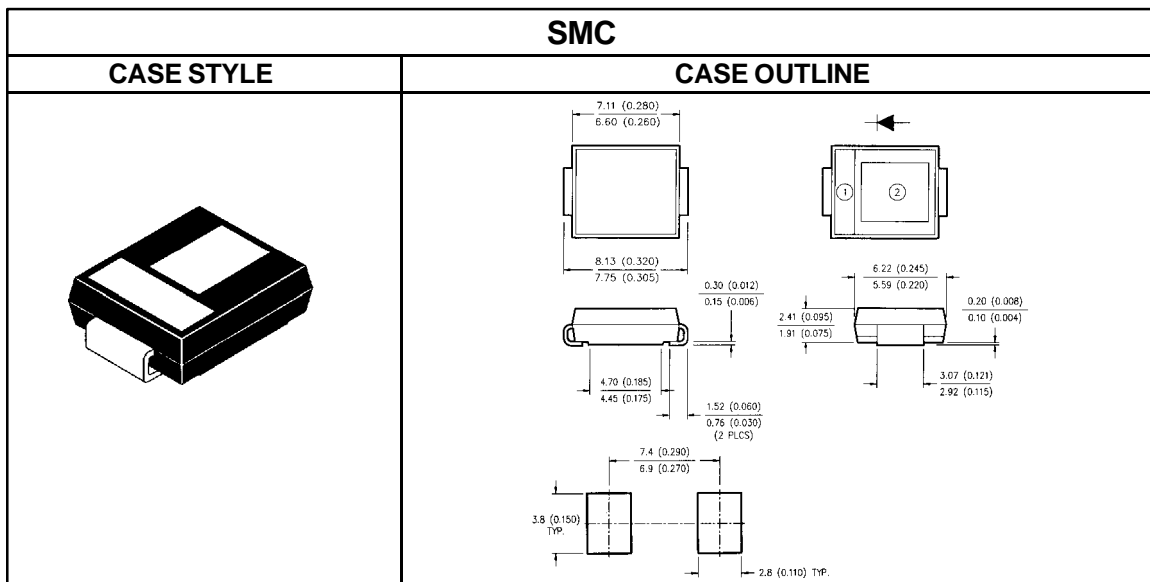
Major Ratings and Characteristics

Characteristics	30BQ100	Units
$I_{F(AV)}$ Rectangular waveform	3.0	A
V_{RRM}	100	V
I_{FSM} @ $t_p = 5\mu s$ sine	2100	A
V_F @ 3.0Apk, $T_J = 125^\circ C$	0.62	V
T_J	-55 to 175	$^\circ C$

Description / Features

The 30BQ100 surface-mount Schottky rectifier has been designed for applications requiring very low forward drop and small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, free-wheeling diodes, battery charging and reverse battery protection.

- Small footprint, surface mountable
- Very low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long-term reliability



30BQ100



Voltage Ratings

Part number	30BQ100
V _R Max. DC Reverse Voltage (V)	100
V _{RRM} Max. Working Peak Reverse Voltage (V)	

Absolute Maximum Ratings

Parameters		30BQ	Units	Conditions
I _{F(AV)}	Max. Average Forward Current See Fig. 5	3.0	A	50% duty cycle @ T _C = 143°C, rectangular waveform
		4.0		50% duty cycle @ T _C = 132°C, rectangular waveform
I _{FSM}	Max. Peak One Cycle Non - Repetitive Surge Current — see Fig. 7	2100	A	5μs Sine or 3μs Rect. pulse 10ms Sine or 6ms Rect. pulse Following any rated load condition and with rated V _{RRM} applied.
		100		
E _{AS}	Non - Repetitive Avalanche Energy	50	mJ	T _J = 25°C, I _{AS} = 2.8A, L = 10mH
I _{AR}	Repetitive Avalanche Current	2.8	A	Current decaying linearly to zero in 1μsec Frequency limited by T _J max. V _A = 1.5 X V _R typical

Electrical Specifications

Parameters		30BQ	Units	Conditions
V _{FM}	Max. Forward Voltage Drop See Fig. 1 ①	0.79	V	@ 3.0A T _J = 25°C
		0.90	V	@ 6.0A
		0.62	V	@ 3.0A T _J = 125°C
		0.70	V	@ 6.0A
I _{RM}	Max. Reverse Leakage Current ① See Fig. 2	0.50	mA	T _J = 25°C V _R = rated V _R
		5.0	mA	T _J = 125°C
C _T	Max. Junction Capacitance	115	pF	V _R = 5V _{DC} , (test signal range 100KHz to 1MHz) 25°C
L _S	Typical Series Inductance	3.0	nH	Measured lead to lead 5mm from package body
dv/dt	Max. Voltage Rate of Change (Rated V _R)	10,000	V/μs	

Thermal-Mechanical Specifications

Parameters		30BQ	Units	Conditions
T _J	Max. Junction Temperature Range	-55 to 100	°C	
T _{STG}	Max. Storage Temperature Range	-55 to 100	°C	
R _{thJA}	Max. Thermal Resistance, Junction to Ambient	12	°C/W	DC operation — See Fig. 4
R _{thJL}	Max. Thermal Resistance, Junction to Lead ②	46	°C/W	DC operation
wt	Approximate Weight	0.24	g	
Case Style		SMC		Similar to DO-214AB

① Pulse Width < 300μs, Duty Cycle < 2%

② Mounted 1 inch square PCB, thermal probe connected to lead 2mm from package

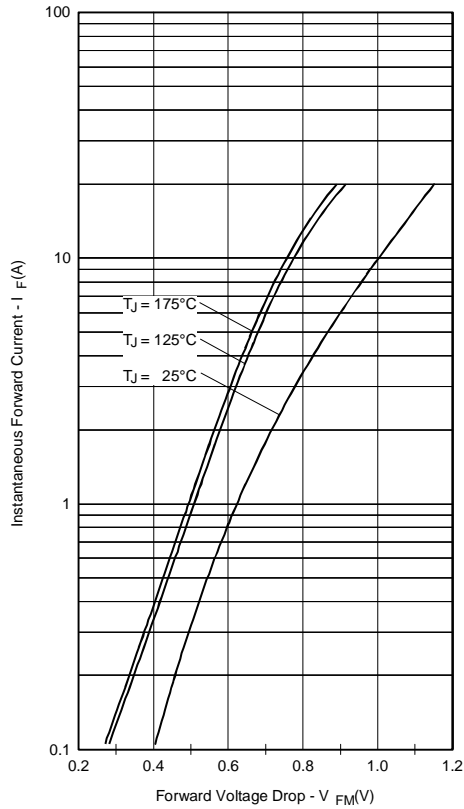


Fig. 1 Max. Forward Voltage Drop Characteristics

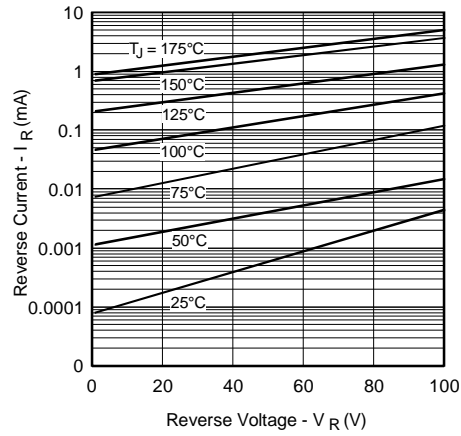


Fig. 2 Typical Values of Reverse Current Vs. Reverse Voltage

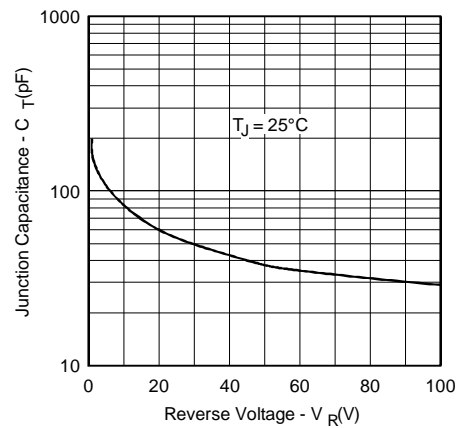


Fig. 3 Typical Junction Capacitance Vs. Reverse Voltage

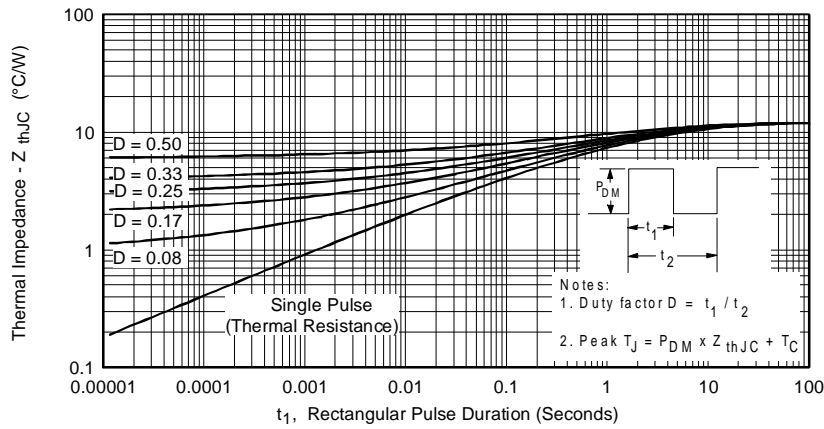


Fig. 4 Max. Thermal Impedance Z_{thJL} Characteristics

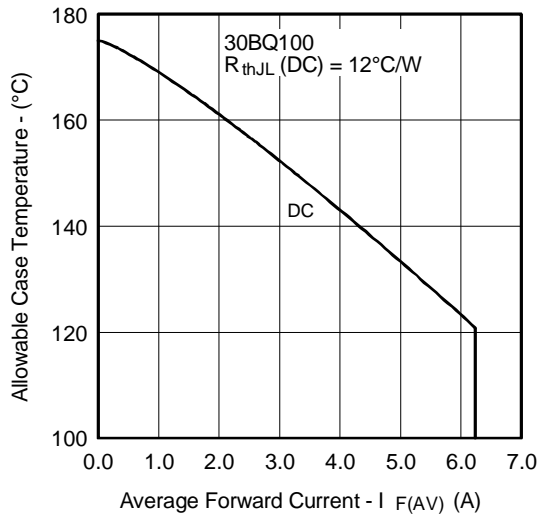


Fig. 5 Max. Allowable Case Temperature Vs. Average Forward Current

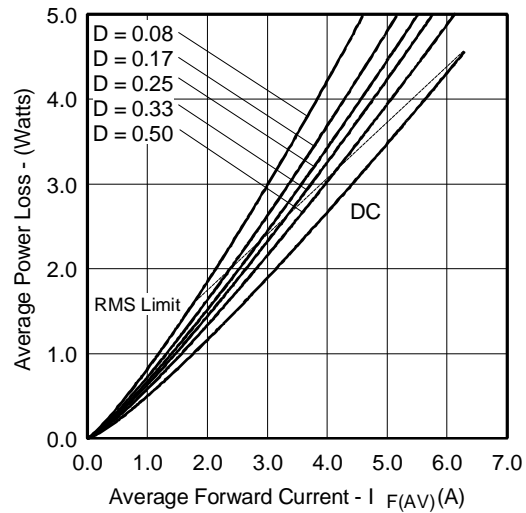


Fig. 6 Forward Power Loss Characteristics

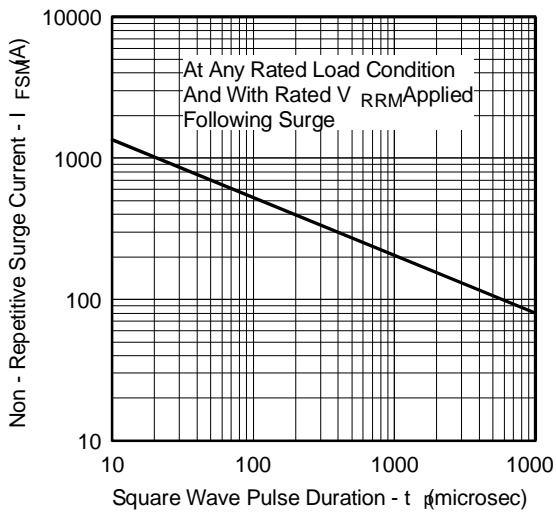


Fig.7 Max. Non-Repetitive Surge Current

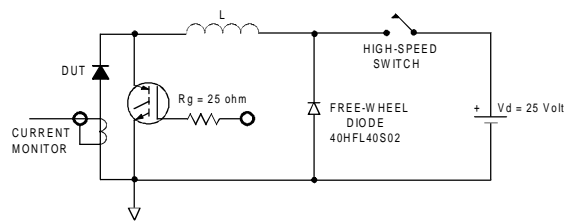


Fig. 8 Unclamped Inductive Test Circuit

Refer to the Appendix Section for the following:

Appendix D: Tape and Reel Information — See page 339.